

### THE AH3367Q IS NOT RECOMMENDED FOR NEW DESIGNS. PLEASE USE THE AH3327Q.

AH3367Q

3. OUTPUT

GND

 $V_{DD}$ 



HIGH-VOLTAGE ULTRA LOW-SENSITIVITY AUTOMOTIVE HALL-EFFECT UNIPOLAR SWITCH

3 OUTPUT

 $1 V_{DD}$ 

(Top View)

SC59 and SOT23

(Top View)

SIP-3 (Bulk Pack)/SIP-3 (Ammo Pack)

GND 2

## Description

The AH3367Q is an AEC-Q100 qualified high-voltage low-sensitivity Hall-effect Unipolar switch IC designed for position and proximity sensing in automotive applications such as in seat and seatbelt buckle, steering lock/immobilization, gear stick, transmission actuator and gear position, HVAC compression, wiper, door/trunk closure, etc. To support the wide range of the demanding applications, the design has been optimized to operate over the supply range of 3.0V to 28V. With chopper stabilized architecture and an internal bandgap regulator to provide temperature compensated supply for internal circuits, the AH3367Q provides a reliable solution over the whole operating range. For robustness and protection, the device has a reverse blocking diode with a Zener clamp on the supply. The output has an overcurrent limit and a Zener clamp.

The single open-drain output can be switched on with South pole of sufficient strength. When the magnetic flux density (B) perpendicular to the package is larger than the operate point (BOP) the output is switched on (pulled low) and is held on until the magnetic flux density B is lower than the release point (BRP). The output remains switched off for North pole fields to or no magnetic fields.

The magnetic operating and release polarity is opposite for SOT23 and SC59 packages. The SOT23, SIP-3 (Ammo Pack) and SIP-3 (Bulk Pack) packages require south pole to the part marking side to operate while SC59 requires south pole to the non-part marking side.

### Features

- Unipolar Operation
- Low Sensitivity: BOP and BRP of 115G and 90G Typical
- Single Open-Drain Output with Overcurrent Limit
- 3.0V to 28V Operating Voltage Range
- **Chopper Stabilized Design Provides** 
  - Superior Temperature Stability
  - Minimal Switch Point Drift
  - Enhanced Immunity to Stress
  - Good RF Noise Immunity
- Reverse Blocking Diode
- Zener Clamp on Supply and Output Pins
- -40°C to +150°C Operating Temperature
- ESD: HBM > 8kV, CDM: > 2kV
- AEC-Q100 Grade 0 Qualified
- Industry Standard SC59, SOT23, SIP-3 (Ammo Pack) and SIP-3 (Bulk Pack) Packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The AH3367Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

## Applications

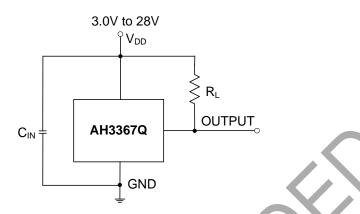
- Position and proximity sensing in automotive applications
- Seat positions
- Seatbelt buckles
- Steering locks/immobilisation
- Gear sticks
- **HVAC** compression
- Transmission actuators
- Transmission gear positions
- Wipers
- Sunroofs and windows
- Door/trunk closure
- Door locks
- Contactless switches

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. Notes:
  - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
    - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Lead-free Green **Pin Assignments** 



## Typical Applications Circuit (Note 4)



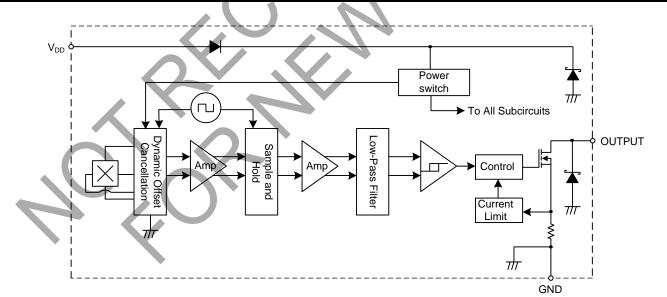
Note: 4. C<sub>IN</sub> is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF to 100nF. RL is the pullup resistor.

## **Pin Descriptions**

Packages: SC59, SOT23, SIP-3 (Ammo Pack) and SIP-3 (Bulk Pack)

Pin Number	Pin Name	Function
1	V <sub>DD</sub>	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

# **Functional Block Diagram**





### Absolute Maximum Ratings (Notes 5 & 6) (@TA = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit		
Vdd	Supply Voltage (Note 6)		32	V		
Vddr	Reverse Supply Voltage (Note 6)		-32	V		
Vout_max	Output Off Voltage (Note 6)		32	V		
Іоит	Continuous Output Current	60	mA			
IOUT_R	Reverse Output Current	-50	mA			
В	Magnetic Flux Density	Unlimited				
PD	Package Power Dissipation	SIP-3 (Ammo Pack) SIP-3 (Bulk Pack)	550	mW		
2		SC59 and SOT23	230			
Ts	Storage Temperature Range		-65 to +165	°C		
TJ	Maximum Junction Temperature	+150	°C			
ESD HBM	Electros Static Discharge Withstand - Human Body M	Electros Static Discharge Withstand - Human Body Model (HBM)				
ESD MM	Electros Static Discharge Withstand - Machine Model	I (MM)	800	V		
ESD CDM	Electros Static Discharge Withstand - Charged Devic	e Model (CDM)	2	kV		

Notes: 5. Stresses greater than those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to Absolute Maximum Ratings for extended periods can affect device reliability. 6. The absolute maximum  $V_{DD}$  of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the

device at the absolute maximum rated conditions for any period of time.

### Recommended Operating Conditions (@TA = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Condition	Rating	Unit
Vdd	Supply Voltage	Operating	3.0 to 28	V
TA	Operating Temperature Range	Operating	-40 to +150	°C

### Electrical Characteristics (Notes 7 & 8) (@TA = -40°C to +150°C, VDD = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Vout_on	Output ON Voltage	1оит = 20mA, B > Вор	_	0.2	0.4	V
Ilkg	Output Leakage Current (When output is off)	Vout = 28V, B < B <sub>RP</sub> , Output off		< 0.1	10	μA
	Supply Current	Output open, T <sub>A</sub> = +25°C		3	3.5	mA
ססו	Supply Culterit	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	mA			
		$V_{DD} = -18V, T_{A} = +25^{\circ}C$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	μA		
<b>I</b> == =	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	0.6	1500	μA		
IDD_R	Reverse Supply Current	$V_{DD} = -28V, T_A = +25^{\circ}C$	_	1.6	—	μA
		$V_{DD} = -28V$ , $T_A = -40^{\circ}C$ to $+150^{\circ}C$	_	1.6	2500	μA
tp_on	Device Power-On Time (Startup time)	V <sub>DD</sub> ≥ 3V, B > B <sub>OP</sub> (Note 7)	_	10	—	μs
fc	Chopping Frequency	—	_	800	—	kHz
tD	(Time from magnetic threshold reached to the start of the output rise	(Note 9)	_	3.75	_	μs
t <sub>R</sub>	(External pullup resistor RL and load	$R_L = 1k\Omega, C_L = 20pF$	_	0.2	1	μs
tF	(Internal switch resistance and load	$R_L = 1k\Omega, C_L = 20pF$	_	0.1	1	μs
IOCL	Output Current Limit	B > B <sub>OP</sub> (Note 10)	30	—	55	mA
Vz	Zener Clamp Voltage	$I_{DD} = 5mA$	28	—	—	V

7. When power is initially turned on, Vop must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid Notes: after the startup time of 10  $\mu s$  typical from the operating voltage reaching 3V.

8. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

9. Guaranteed by design, process control and characterization. Not tested in production.

10. The device will limit the output current IOUT to current limit of IOCL.



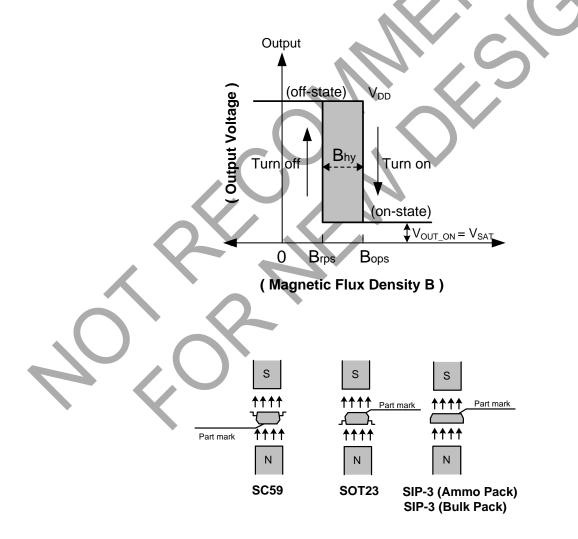
### **Magnetic Characteristics** (Notes 11 & 12) (T<sub>A</sub> = -40°C to +150°C, V<sub>DD</sub> = 3.0V to 28V, unless otherwise specified.)

				(1m	nT = 10 Ga	auss)
Symbol	Parameter	Condition	Min	Тур	Мах	Unit
B <sub>OPS</sub>		$V_{DD} = 12V, T_A = +25^{\circ}C$	—	115	—	
(South pole to the part marking side for SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) packages; South pole to the non-part marking side for SC59 package. See diagram below)	Operation Point	$T_A = -40^{\circ}C \text{ to } +150^{\circ}C$	95	115	140	
B <sub>RPS</sub>		$V_{DD} = 12V, T_A = +25^{\circ}C$	-	90	_	Gauss
(South pole to the part marking side for SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) packages; South pole to the non-part marking side for SC59 package. See diagram below)	Release Point	T <sub>A</sub> = -40°C to +150°C	70	90	120	Gauss
	Livetoracia (Nieto 12)	V <sub>DD</sub> = 12V, T <sub>A</sub> = +25°C	<b>-</b>	25	—	
Bhy ( Bopx - Brpx )	Hysteresis (Note 13)	T <sub>A</sub> = -40°C to +150°C	18	25	36	

Notes: 11. When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the startup time of 10µs typical from the operating voltage reaching 3V.

12. Typical values are defined at  $T_A = +25^{\circ}C$ ,  $V_{DD} = 12V$ . Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

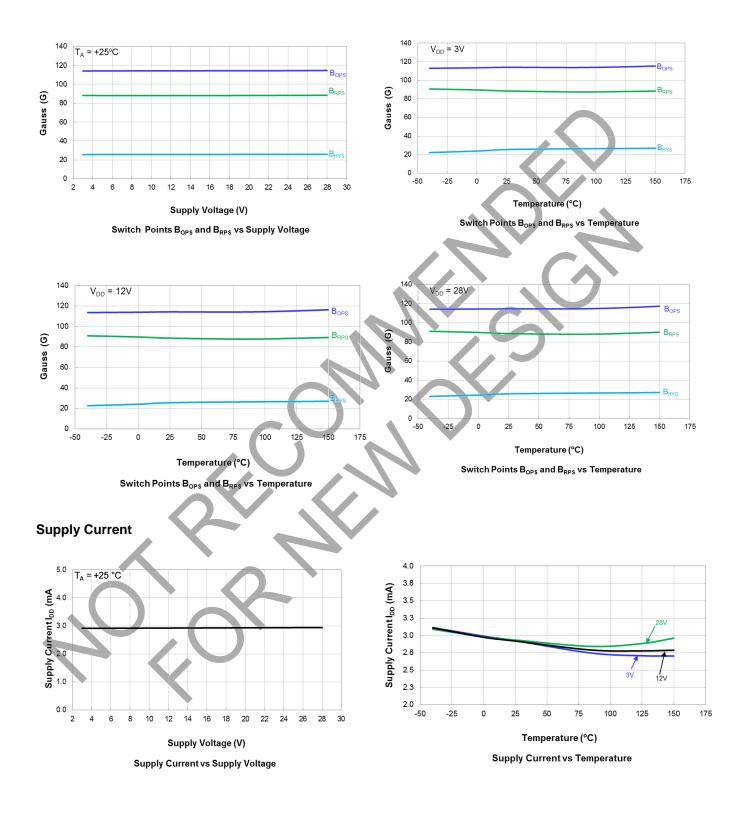
13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.





## **Typical Operating Characteristics**

### Output Switch Operate and Release Points (Magnetic Thresholds) – BOPS and BRPS

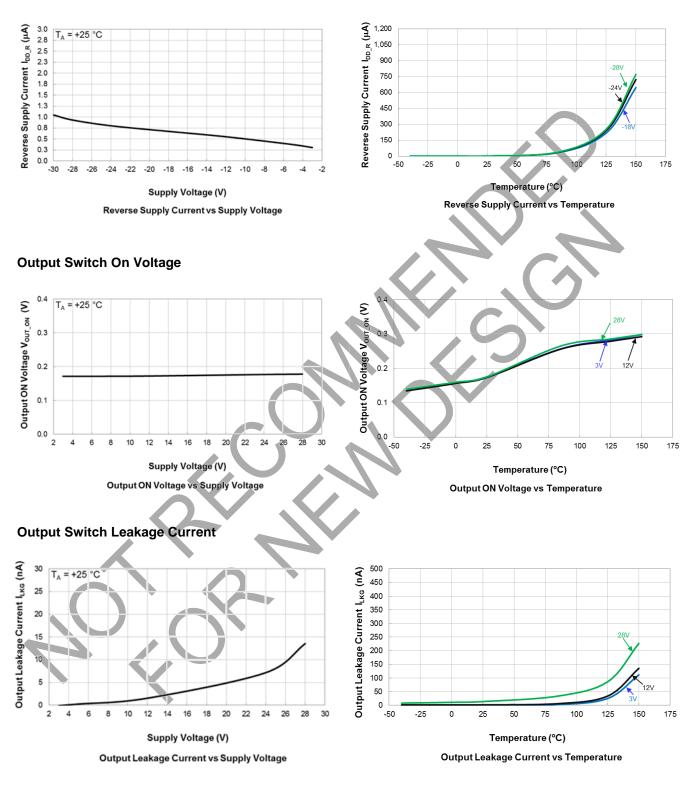




AH3367Q

### Typical Operating Characteristics (continued)

### **Supply Reverse Current**

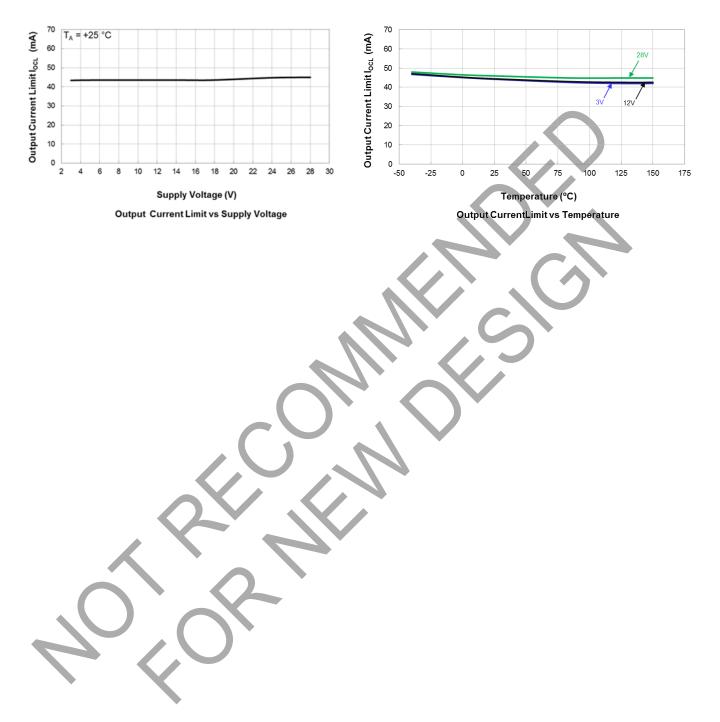




AH3367Q

## Typical Operating Characteristics (continued)

### **Output Current Limit**

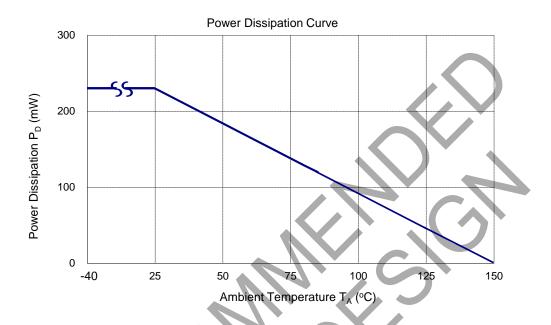




## **Thermal Performance Characteristics**

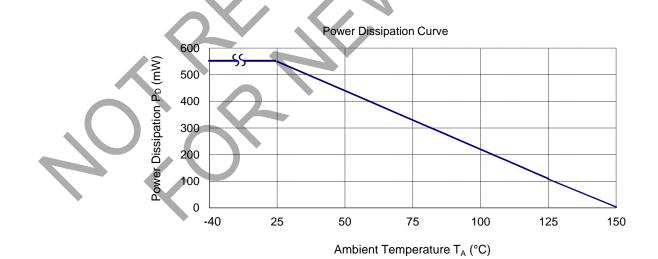
### (1) Package Types: SC59 and SOT23

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



#### (2) Package Types: SIP-3 (Ammo Pack) and SIP-3 (Bulk Pack)

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0

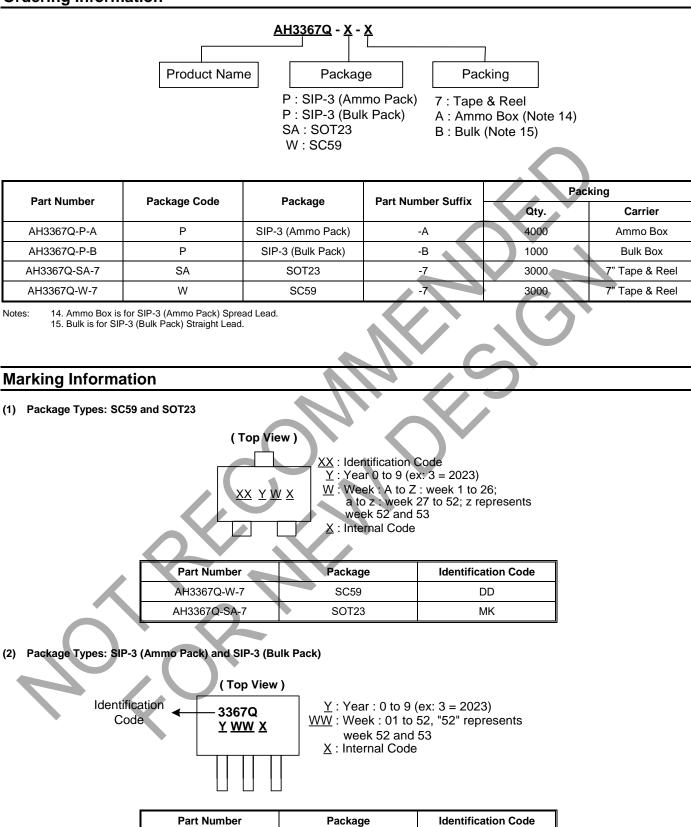




## **Ordering Information**

Notes:

(2)



AH3367Q-P-A

AH3367Q-P-B

SIP-3 (Ammo Pack)

SIP-3 (Bulk Pack)

3367Q

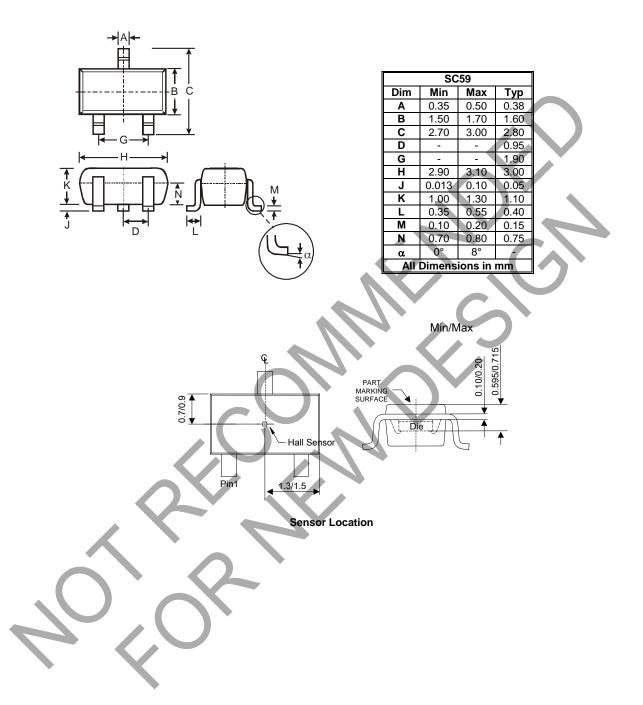
3367Q



## Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SC59

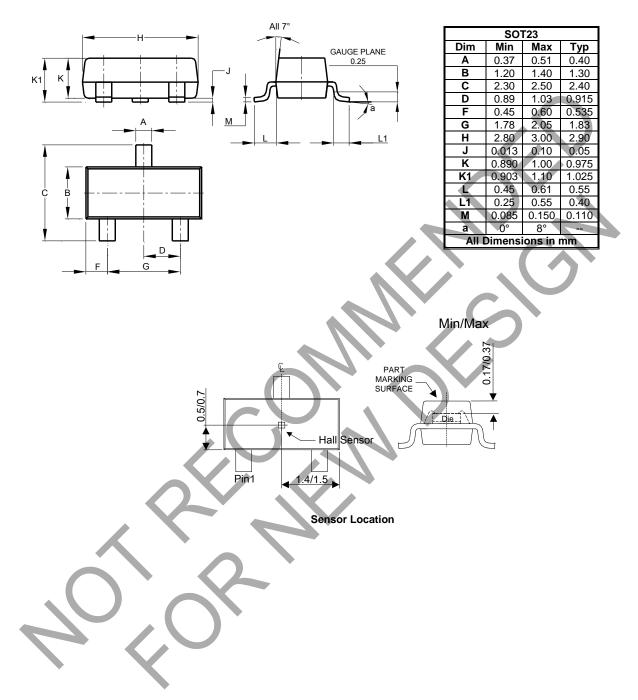




## Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (2) Package Type: SOT23

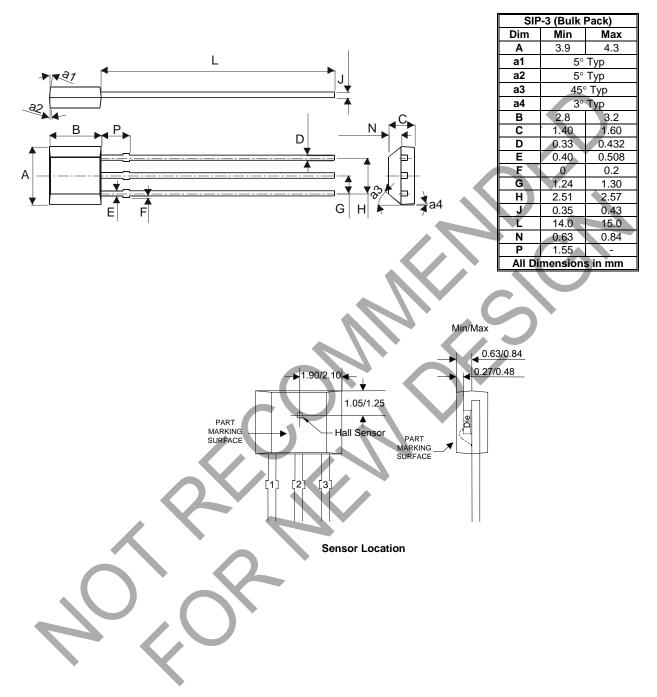




## Package Outline Dimensions (continued) (All dimensions in mm.)

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#### (3) Package Type: SIP-3 (Bulk Pack)

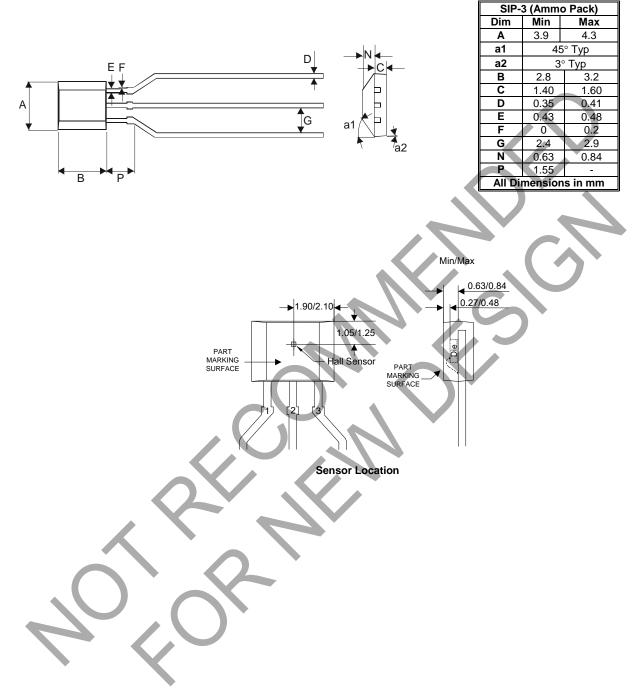




## Package Outline Dimensions (continued) (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (4) Package Type: SIP-3 (Ammo Pack)

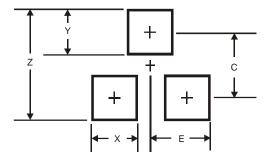




## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

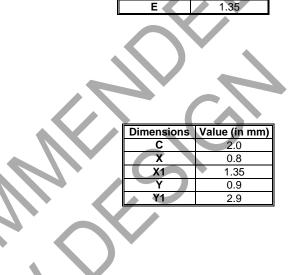
#### (1) Package Type: SC59



C

#### (2) Package Type: SOT23

Y1



Dimensions Value (in mm)

Z X Y

С

3.4 0.8

1.0

2.4



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